NSN 5961-01-089-0776

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-089-0776

Inclosure Material:

Metal

Overall Length:

Between 1.360 inches and 1.375 inches

Overall Height:

0.712 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 collector to base voltage/static/emitter open and 9.0 emitter to base voltage, static, collector open and 400.0 collector-to-emitter,

substaining voltage, base open-circuited

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0